Transistor - Page 1 of 2



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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

## **Overall Height:**

0.450 inches

#### **Overall Width:**

1.050 inches

#### **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact-darlington connected

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

-60.0 collector to emitter voltage/static/base open and -60.0 collector to base voltage, dc and -5.0 emitter to base voltage, dc

# **Current Rating Per Characteristic:**

16.00 amperes source cutoff current and 0.50 amperes source cutoff current

## Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Precious Material And Location:**

Terminal surface option gold

#### **Precious Material:**

Gold

# Test Data Document:

06401-7905505 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# **Terminal Type And Quantity:**

2 pin and 1 case

# Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

# **NSN 5961-01-107-5116** Transistor - Page 2 of 2

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